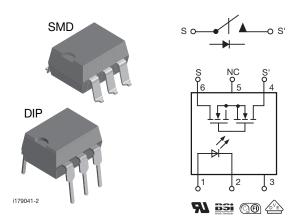
## LH1550AAB1, LH1550AAB1TR, LH1550AT1

Vishay Semiconductors

# 1 Form A High-Voltage Solid-State Relay



#### **DESCRIPTION**

The LH1550 is robust, ideal for telecom and ground fault applications. It is an SPST normally open switch (1 form A) that replaces electromechanical relays in many applications. It is similar to the LH1540, but has a characteristically higher On resistance. It is constructed using a GaAlAs LED for actuation control and an integrated monolithic die for the switch output. The die, fabricated in a high-voltage dielectrically isolated technology, is comprised of a photodiode array, switch control circuitry and MOSFET switches. In addition, it employs current-limiting circuitry which meets lightning surge testing as per ANSI/TIA-968-B and other regulatory voltage surge requirements when overvoltage protection is provided.

#### **FEATURES**

- · Current limit protection
- Isolation test voltage 5300 V<sub>RMS</sub>
- Typical R<sub>ON</sub> 28 Ω
- Load voltage 350 V
- Load current 120 mA
- · High surge capability
- · Clean bounce free switching
- Low power consumption
- SMD lead available on tape and reel
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



- · General telecom switching
- Instrumentation
- · Industrial controls

### **AGENCY APPROVALS**

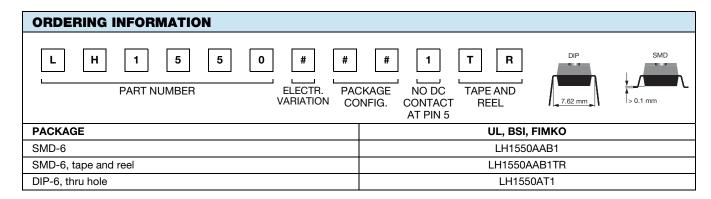
UL1577: file no. E52744 system code H, double protection

BSI: 7979/7980

DIN EN: 60747-5-2 (VDE 0884)/60747-5-5 (pending),

available with option 1

FIMKO: 25419



| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                        |                |       |      |  |  |  |
|--|------------------------|----------------|-------|------|--|--|--|
| PARAMETER  | TEST CONDITION         | SYMBOL         | VALUE | UNIT |  |  |  |
| INPUT  |                        |                |       |      |  |  |  |
| LED continuous forward current   |                        | I <sub>F</sub> | 50    | mA   |  |  |  |
| LED reverse voltage  | I <sub>R</sub> ≤ 10 μA | $V_{R}$        | 8     | V    |  |  |  |
| OUTPUT   |                        |                |       |      |  |  |  |
| DC or peak AC load voltage   | $I_L \le 50 \ \mu A$   | $V_L$          | 350   | V    |  |  |  |
| Continuous DC load current - bidirectional operation                                   |                        | IL             | 100   | mA   |  |  |  |
| Peak load current (single shot)  | t = 100 ms             | l <sub>P</sub> | (1)   |      |  |  |  |



# LH1550AAB1, LH1550AAB1TR, LH1550AT1

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| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |               |                  |  |  |  |
|--|---|-------------------|---------------|------------------|--|--|--|
| PARAMETER  | TEST CONDITION                            | SYMBOL            | VALUE         | UNIT             |  |  |  |
| SSR  |   |                   |               |                  |  |  |  |
| Ambient temperature range  |   | T <sub>amb</sub>  | - 40 to + 85  | °C               |  |  |  |
| Storage temperature range  |   | T <sub>stg</sub>  | - 40 to + 150 | °C               |  |  |  |
| Pin soldering temperature (2)  | t = 10 s max.                             | T <sub>sld</sub>  | 260           | °C               |  |  |  |
| Input to output isolation voltage  | $V_{RMS}$ t = 1 s, $I_{ISO}$ = 10 $\mu$ A | V <sub>ISO</sub>  | 5300          | V <sub>RMS</sub> |  |  |  |
| Output power dissipation (continuous)  |   | P <sub>diss</sub> | 550           | mW               |  |  |  |

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to current limit performance application note 58 for a discussion on relay operation during transient currents.
- (2) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                   |       |      |      |      |  |
|--|---|-------------------|-------|------|------|------|--|
| PARAMETER  | TEST CONDITION  | SYMBOL            | MIN.  | TYP. | MAX. | UNIT |  |
| INPUT  |   |                   |       |      |      |      |  |
| LED forward current, switch turn-on  | $I_L = 100 \text{ mA}, t = 10 \text{ ms}$                 | I <sub>Fon</sub>  |       | 1.1  | 2    | mA   |  |
| LED forward current, switch turn-off   | $V_{L} = \pm 350 \text{ V}$                               | I <sub>Foff</sub> | 0.001 | 1    |      | mA   |  |
| LED forward voltage  | I <sub>F</sub> = 10 mA                                    | $V_{F}$           | 1.15  | 1.25 | 1.45 | V    |  |
| OUTPUT   |   |                   |       |      |      |      |  |
| On-resistance, AC: pin 4 (±) to 6 (±)  | $I_F = 5 \text{ mA}, I_L = 50 \text{ mA}$                 | R <sub>ON</sub>   |       | 28   | 50   | Ω    |  |
| Off-resistance   | $I_F = 0 \text{ mA}, V_L = \pm 100 \text{ V}$             | R <sub>OFF</sub>  | 0.5   | 300  |      | GΩ   |  |
| Current limit AC (1): pin 4 (±) to 6 (±)   | $I_F = 5 \text{ mA}, t = 5 \text{ ms}, V_L = 6 \text{ V}$ | I <sub>LMT</sub>  | 170   | 210  | 250  | mA   |  |
| Off-state leakage current  | $I_F = 0 \text{ mA}, V_L = \pm 100 \text{ V}$             | Io                |       | 0.35 | 200  | nA   |  |
|  | $I_F = 0 \text{ mA}, V_L = \pm 350 \text{ V}$             | I <sub>O</sub>    |       | 0.09 | 1    | μΑ   |  |
| Output capacitance pin 4 to 6  | $I_F = 0 \text{ mA}, V_L = 1 \text{ V}$                   | Co                |       | 18   |      | pF   |  |
|  | $I_F = 0 \text{ mA}, V_L = 50 \text{ V}$                  | Co                |       | 7    |      | pF   |  |
| Switch offset  | I <sub>F</sub> = 5 mA                                     | V <sub>OS</sub>   |       | 0.3  |      | μV   |  |
| TRANSFER   |   |                   |       |      |      |      |  |
| Capacitance (input to output)  | V <sub>ISO</sub> = 1 V                                    | C <sub>IO</sub>   |       | 0.7  |      | pF   |  |

#### Notes

<sup>(1)</sup> No DC mode current limit available.

| <b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |   |                  |      |      |      |      |
|---|---|------------------|------|------|------|------|
| PARAMETER   | TEST CONDITION                            | SYMBOL           | MIN. | TYP. | MAX. | UNIT |
| Turn-on time  | $I_F = 5 \text{ mA}, I_L = 50 \text{ mA}$ | t <sub>on</sub>  |      | 1.1  | 3    | ms   |
| Turn-off time   | $I_F = 5 \text{ mA}, I_L = 50 \text{ mA}$ | t <sub>off</sub> |      | 0.7  | 3    | ms   |

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluations. Typical values are for information only and are not part of the testing requirements.

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| PARAMETER   |                  | TEST CONDITION   | SYMBOL            | VALUE              | UNIT              |
|---|------------------|--|-------------------|--------------------|-------------------|
| Climatic classification   |                  | IEC 68 part 1  |                   | 40/85/21           |                   |
| Pollution degree  |                  | DIN VDE 0109   |                   | 2                  |                   |
| Tracking resistance (comparative tracking index)                                |                  | Insulation group IIIa  | СТІ               | 175                |                   |
| Highest allowable overvoltage   |                  | Transient overvoltage  | V <sub>IOTM</sub> | 8000               | V <sub>peak</sub> |
| Max. working insulation voltage   |                  | Recurring peak voltage   | V <sub>IORM</sub> | 890                | V <sub>peak</sub> |
| Insulation resistance at 25 °C  |                  |  | R <sub>IS</sub>   | ≥ 10 <sup>12</sup> | Ω                 |
| Insulation resistance at T <sub>S</sub>   |                  | V <sub>IO</sub> = 500 V  | R <sub>IS</sub>   | ≥ 10 <sup>9</sup>  | Ω                 |
| Insulation resistance at 100 °C   |                  |  | R <sub>IS</sub>   | ≥ 10 <sup>11</sup> | Ω                 |
| Partial discharge test voltage  |                  | Methode a, V <sub>pd</sub> = V <sub>IORM</sub> x 1.875                               | $V_{pd}$          | 1669               | V <sub>peak</sub> |
| Safety limiting values -<br>maximum values allowed<br>in the event of a failure | Case temperature |  | T <sub>SI</sub>   | 175                | °C                |
|   | Input current    |  | I <sub>SI</sub>   | 300                | mA                |
|   | Output power     |  | P <sub>SO</sub>   | 700                | mW                |
| Minimum external air gap (clearance)  |                  | Measured from input terminals to output terminals, shortest distance through air     |                   | ≥ 7                | mm                |
| Minimum external tracking (creepage)  |                  | Measured from input terminals to output terminals, shortest distance path along body |                   | ≥ 7                | mm                |

## **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

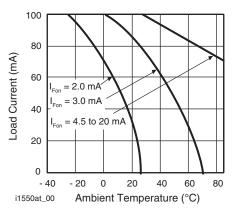


Fig. 1 - Recommended Operating Conditions

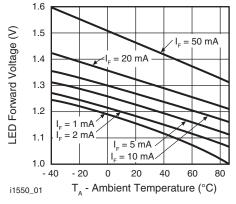


Fig. 2 - LED Voltage vs. Temperature

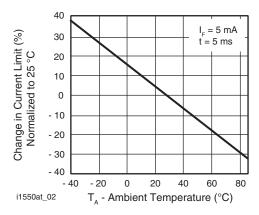


Fig. 3 - Current Limit vs. Temperature

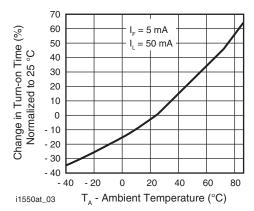


Fig. 4 - Turn-on Time vs. Temperature



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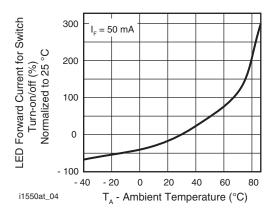


Fig. 5 - LED Current for Switch Turn-on vs. Temperature

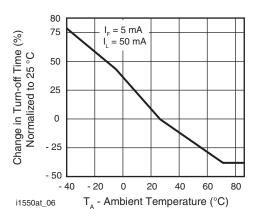


Fig. 7 - Turn-off Time vs. Temperature

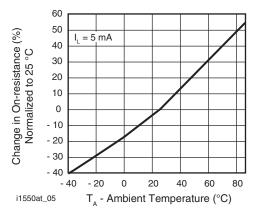
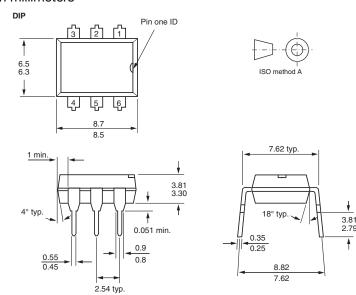


Fig. 6 - On-resistance vs. Temperature

i178001

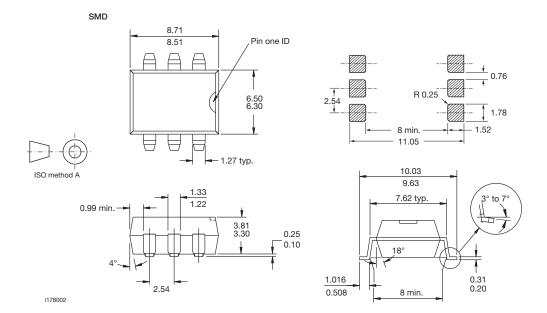
### **PACKAGE DIMENSIONS** in millimeters





# LH1550AAB1, LH1550AAB1TR, LH1550AT1

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### **PACKAGE MARKING**



### Note

• Tape and reel suffix (TR) is not part of the package marking.





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Revision: 11-Mar-11

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